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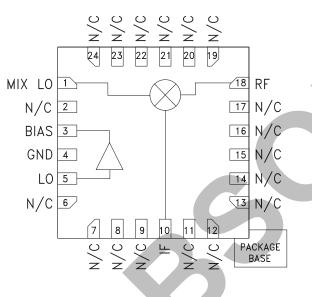


#### **Typical Applications**

The HMC215LP4 / HMC215LP4E is ideal for Wireless Infrastructure Applications:

- PCS / 3G Infrastructure
- Base Stations & Repeaters
- WiMAX & WiBro
- ISM & Fixed Wireless

#### **Functional Diagram**



# HMC215LP4 / 215LP4E

### GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 1.7 - 4.0 GHz

#### Features

Input IP3: +25 dBm Low Input LO Drive: +2 to +6 dBm High LO to RF Isolation: 32 dB Low Conversion Loss: 8 dB Single Positive Supply: +5V @ 56 mA 24 Lead Ceramic 4x4mm SMT Package: 16mm<sup>2</sup>

#### **General Description**

The HMC215LP4 & HMC215LP4E are high linearity, double-balanced converter ICs that operate from 1.7 to 4.0 GHz and deliver a +25 dBm input third order intercept point. The LO amplifier output and high dynamic range mixer input are positioned so that an external LO filter can be placed in series be-tween them. The converter provides 32 dB of LO to RF isolation and is ideal for upconverter and down-converter applications. The IC operates from a single +5V supply consuming 56 mA of current and accepts a LO drive level of 2 to 6 dBm. The design requires no external baluns and supports IF frequencies between DC and 1 GHz. The HMC215LP4(E) is pin for pin compatible with the HMC552LP4(E), which operates from 1.6 to 3.0 GHz.

#### Electrical Specifications, $T_A = +25^{\circ}C$ , $LO = +4 \, dBm$ , Vcc = +5V, $IF = 100 \, MHz^*$

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF, LO		1.7 - 4.0		GHz
Frequency Range, IF		DC - 1.0		GHz
Conversion Loss		8.0	11	dB
Noise Figure (SSB) 8.5		8.5		dB
LO to RF Isolation	23	32		dB
LO to IF Isolation	10	20		dB
IP3 (Input)		25		dBm
1 dB Compression (Input)	npression (Input) 17		dBm	
LO Drive Input Level (Typical)	2 to 6			dBm
Supply Current (Icc)		56	60	mA

\*Unless otherwise noted, all measurements performed as a downconverter, with low side LO and configured as shown in application circuit.

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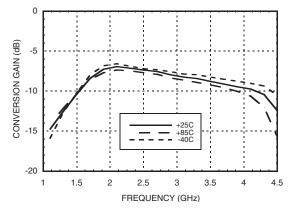


### GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 1.7 - 4.0 GHz

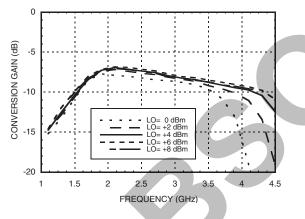


#### Conversion Gain vs. Temperature

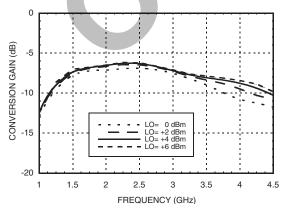
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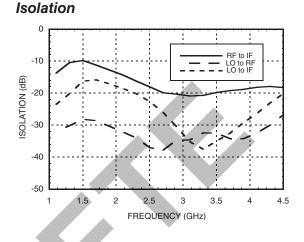


#### Conversion Gain vs. LO Drive

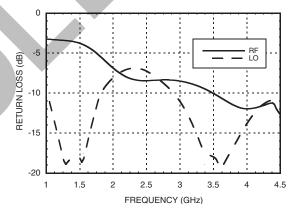


#### Upconverter Performance Conversion Gain vs. LO Drive

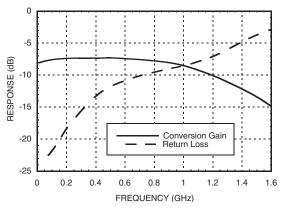




Return Loss







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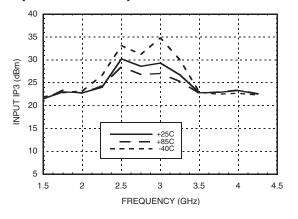
LO AMPLIFIER, 1.7 - 4.0 GHz

GaAs MMIC MIXER w/ INTEGRATED

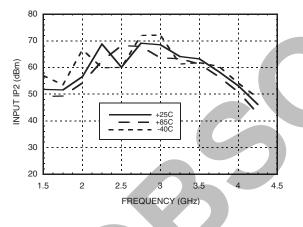
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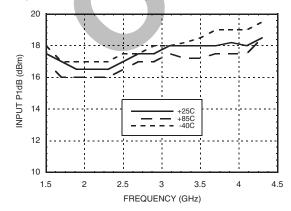
#### Input IP3 vs. Temperature



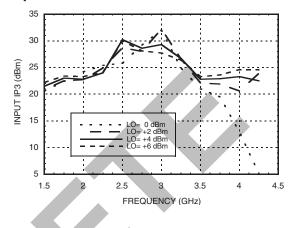
#### Input IP2 vs. Temperature



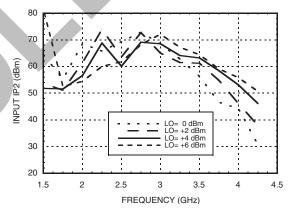
#### Input P1dB vs. Temperature



#### Input IP3 vs. LO Drive



#### Input IP2 vs. LO Drive



#### MxN Spurious @ IF Port

	nLO					
mRF	0	1	2	3	4	
0	xx	-4	10	14	32	
1	5	0	22	37	49	
2	78	66	60	63	93	
3	83	97	92	80	80	
4	103 101 106 105 101					
RF Freq. = 1.9 GHz @ -10 dBm LO Freq. = 1.8 GHz @ 4 dBm All values in dBc relative to the IF power level.						

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10 - 3



LO AMPLIFIER. 1.7 - 4.0 GHz

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v01.0111



#### Harmonics of LO

	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
1.0	32	40	27	40
1.4	28	19	25	30
1.8	29	16	30	42
2.2	33	18	27	44
2.6	35 23 34 41			
<b>3.0 34 20 41 44</b>				
LO = 4 dBm All values in dBc below input LO level measured at RF port.				



**Outline Drawing** 

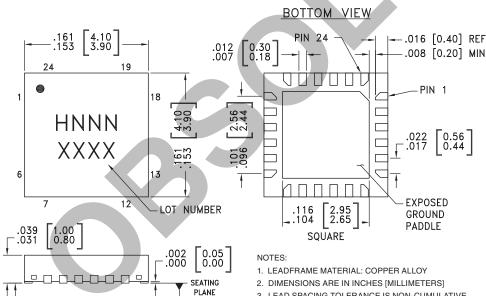
#### ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

#### **Typical Supply Current**

Vcc	Icc (mA)
+5.0	56 mA

#### Absolute Maximum Ratings

	<b>_</b>
RF / IF Input (Vcc= +5V)	+22 dBm
LO Drive (Vcc= +5V)	+10 dBm
BIAS	+7 Vdc
Junction Temperature	150°C
Continuous Pdiss (T = 85°C) (derate 5.21 mW/°C above 85°C)	0.339 W
Thermal Resistance (junction to ground paddle)	192 °C/W
Storage Temperature	-65 to +150°C
Operating Temperature	-40 to +85°C



-C-

- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURB HEIGHT SHALL BE 0.05mm MAXIMUM
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### Package Information

.003[0.08]C

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Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC215LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H215 XXXX
HMC215LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>H215</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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10



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### GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 1.7 - 4.0 GHz



#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	MIX LO	This pin is DC coupled and matched to 50 Ohms. An off chip DC blocking capacitor is required.	MIX LOO
2, 6 - 9, 11 - 17, 19 - 24	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	
3	BIAS	Power supply for the LO amplifier. Three external bypass capacitors are recommended for optimum performance, as illustrated in the application circuit.	BIASO
4	GND	Backside of package has exposed metal ground paddle that must also be connected to ground.	
5	LO	This pin is DC coupled and matched to 50 Ohms from 1.7 to 4.0 GHz. An off chip DC blocking capacitor is required.	LOO
10	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source/sink more than 18 mA of current or die non-function and possible die failure will result.	
18	RF	This pin is DC coupled and matched to 50 Ohms.	RF O
Applicatior	n Circuit		
		MIX LO (PIN1)	

Vcc O-~~	$\begin{array}{c}1\\$	$\neg$	(PIN18)
Recommended Components	Values (IF = DC - 300 MHz)	6	
C3	1000 pF	IF (PIN10)	
C4	2.2 μF		
C1, C2, C5	100 pF		
L1	18 nH		

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18 Ohm

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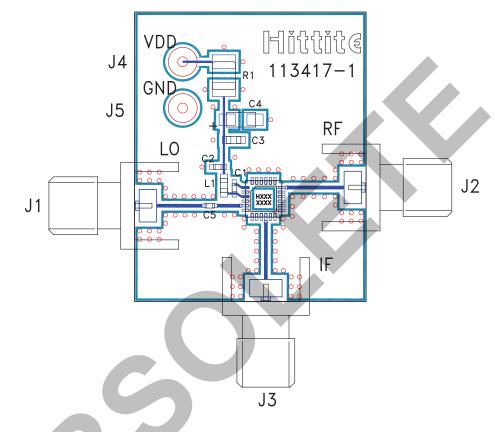


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### GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 1.7 - 4.0 GHz

### Evaluation PCB



#### List of Materials for Evaluation PCB 115820<sup>[1]</sup>

Description	
J1 - J3 PCB Mount SMA RF Connector	
DC Pin	
100 pF Chip Capacitor, 0402 Pkg.	
C3 1000 pF Chip Capacitor, 0603 Pkg.	
C4 2.2 µF Capacitor, Tantalum	
18 nH Chip Inductor, 0603 Pkg.	
18 Ohm Resistor, 1210 1/8 watt Pkg.	
HMC215LP4 / HMC215LP4E	
113417 Evaluation Board	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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